NSN 5962-01-531-1064

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View Online at https://aerobasegroup.com/nsn/5962-01-531-1064

Body Length:
0.540 inches
Body Width:
0.300 inches
Body Height:
0.092 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
F-15 avionics
Features Provided:
Hermetically sealed and burn in and monolithic and positive outputs
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Case Outline Source And Designator:
F-9 mil-m-38510
Current Rating Per Characteristic:
100.00 milliamperes forward current, peak total value not applicable
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital, bipolar progammable logic, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
30.00 nanoseconds delay
Memory Device Type:
Pal
Special Features:
Program using cage 82577 dwg pt5059108-00-80
Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type And Quantity:

20 flat leads

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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